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(Published 4 June 1999)

CONTENTS

- **Editorial Note**
- A. Yacoby, H.F. Hess, T.A. Fulton, L.N. Pfeiffer and K.W. West
- Š. Pick
- 15 method into the recursion-technique scheme
- T. Heine, P.W. Fowler and G. Seifert
- M. Maaza, J.P. Chauvineau, B. Pardo, A. Raynal,
- A. Menelle, F. Bridou and J. Corno
- M. Grottel and R. Jakubas
- A. Tiwari and K.P. Rajeev
- W. Kempiński
- V. Damodara Das and S. Selvaraj
- V.V. Krivolapchuk, E.S. Moskalenko,
- A.L. Zhmodikov, T.S. Cheng and C.T. Foxon
- S. Lotha, A. Ingale, D.K. Avasthi, V.K. Mittal,
- S. Mishra, K.C. Rustagi, A. Gupta,
- V.N. Kulkarni and D.T. Khathing

- Electrical imaging of the quantum Hall state 1
- Magnetic anisotropy calculation: implementation of the torque
- 19 C₃₆: from dimer to bulk
- 23 V-Ni multilayered monochromators and supermirrors for cold neutrons
- 29 NMR study of the pyridinium cation motions in $(C_5H_5NH)_6Bi_4Cl_{18}$
- 33 Low-temperature electrical transport in La_{0.7}A_{0.3}MnO₃, (A: Ca, Sr, Ba)
- 39 Intercalation of C₆₀ by alkali metals: kinetics of transient states formation
- 43 Electrical conduction studies on Bi₂(Te_{0.8}Se_{0.2})₃ chalcogenide thin films
- 49 Collective properties of spatially indirect excitons in asymmetric GaAs/AlGaAs double quantum wells
- 55 Effect of heavy ion irradiation on C₆₀

Keywords

VOLUME 111, NUMBER 2

(Published 8 June 1999)

CONTENTS

- M. Haddad, R. André, R. Frey and C. Flytzanis

D.B. Tran Thoai and H. Thien Cao

- A.R. Pereira and A.S.T. Pires
- G. Srinivasan, S.K. Georgiadis and M. Hildebrandt
- P.S. Goyal, V.K. Aswal, A. Inaba, W. Kagunya and C.J. Carlile
- T.W. Kim and M. Jung
- L. Kovács, S. Erdei and R. Capelletti,
- Y.-M. Zhou, S.-C. Wu and D.-S. Wang
- M. Polomska, J.-L. Sauvajol, A. Graja and A. Girard 107
- C. Ji, J. Yang, W. Mao and Y. Yang

- Enhanced Faraday rotation in an asymmetric semiconductor microcavity
- 67 Subband renormalization of highly excited quantum-well wires
- Magnon waveforms in the presence of a vortex-pair in easyplane antiferromagnets
- 79 Magnetic properties of the mixed oxide LaMnO₃-ABO₃ (AB=PbZr, BaTi)
- 85 Tunnelling states and anomalous specific heat of disordered solids at low temperatures
- 89 Magnetotransport studies of the two-dimensional electron gas in modulation-doped Al_xGa_{1-x}As/In_yGa_{1-y}As/GaAs asymmetric step quantum wells
- 95 OH vibrational band in YVO4 crystals
- First principles calculation of the interface state in fcc-Fe/ 101 Cu(111)
 - Resonant Raman scattering from single crystals (Ph₄P)₂·C₆₀·Y, where Y=Cl, Br, I
- 113 Micromagnetic study of Nd₂Fe₁₄B/α-Fe and Nd₂Fe₁₄B/Fe₃B nanocomposite magnets
 - Keywords I

(Published 16 June 1999)

CONTENTS

T. Kraft and J. Walter	119	Raman spectroscopic investigation of TaCl ₅ –GIC and products of its partial hydrolysis
G. Park, J. Sel, S. Bu and IH. Song	125	Dielectric properties of $(K_{0.4}Na_{0.6})_2(Sr_{0.6}Ba_{0.4})_4Nb_{10}O_{30}$ thin films fabricated by RF magnetron sputtering method
T. Saito, Y. Akita, M. Tokumoto, P.W. Stephens and K. Tanaka	131	Synthesis and characterization of liquid-phase prepared RbC ₆₀
T. Yamamoto, T. Tanaka, T. Matsuyama, T. Funabiki and S. Yoshida	137	XAFS study of the structure of the silica-supported ytterbium oxide catalyst
K. Nomura and H. Kamimura	143	Tight-binding Hamiltonians for superconducting YBa ₂ Cu ₃ O ₇
M. Drulis, W. Iwasieczko, P. Gaczyński and H. Drulis	149	Intermediate valence in the ytterbium hydride—the specific heat evidence
Y. Echizen, K. Umeo and T. Takabatake	153	Superconductivity and magnetoresistance in a single-crystal LaNiSn
Y. Zhao, C.H. Cheng and H. Zhang	159	Influences of flux flow on a.c. loss per cycle in superconductors
W. Mao, C. Ji, H. Chang, B. Cheng, Y. Yang, L. Wang, F. Li, H. Du, Y. Xue and B. Zhang	165	Study on the magnetic moments of $PrFe_{10.5}V_{1.5}$ and $PrFe_{10.5}V_{1.5}N_x$ compounds
H. Qin, X. Gu, H. Lu, J. Liu, X. Huang and K. Chen	171	Observation of Coulomb-blockade in a field-effect transistor with silicon nanocrystal floating gate at room temperature
	I	Keywords

VOLUME 111, NUMBER 4

(Published 18 June 1999)

N. Tomita and K. Nasu	175	Difference between the small one-electron gap and the large optical gap in one-, two-, and three-dimensional half-filled Hubbard models
I. Loa, S. Gronemeyer, C. Thomsen and R.K. Kremer	181	Low-energy magnetic excitations in the dimerized and incommensurate phase of CuGeO ₃
U. Hohenester, F. Rossi and E. Molinari	187	Few-particle effects in the optical spectra of semiconductor quantum dots
L.R. Tessler	193	The origin of visible photoluminescence in low power $a-Si_{1-x}C_x$:H with $x>0.2$
D. Djajaputra and J. Ruvalds	199	Spin susceptibility divergence in high-temperature super- conductors
A. Pietraszko and W. Bronowska	205	Rb ₂ Li ₄ (SeO ₄) ₃ 2H ₂ O—the new crystal of selenates hydrates family
G. Ghislotti, D. Ielmini, E. Riedo, M. Martinelli and M. Dellagiovanna	211	Picosecond time-resolved luminescence studies of recombina- tion processes in CdTe
E.S. Rodrigues, E.V. Anda, P. Orellana and H.N. Nazareno	217	Non-linear effects in resonant tunnelling through a quantum dot
Y.C. Wang, W.C. Hwang, Z.P. Yang, G.S. Chang and J.S. Hwang	223	Studies of lattice-matched InGaAs/InAlAs single quantum well by photoreflectance spectroscopy and wet chemical etching
T.H. Yeom, I.G. Kim, S.H. Choh, K.S. Hong, Y.J. Park and SK. Min	229	Nuclear magnetic relaxation studies of ⁶⁹ Ga, ⁷¹ Ga, and ⁷⁵ As nuclei in GaAs single crystals doped with paramagnetic impurities

I Author Index

III Keywords

VOLUME 111, NUMBER 5

(Published 2 July 1999)

CONTENTS

B. Thomas, K. Ellmer, W. Bohne, J. Röhrich, M. Kunst and H. Tributsch	235	Photoeffects in cobalt doped pyrite (FeS ₂) films
Z.P. Guan, G.K. Kuang, E. Griebl, M.J. Kastner and W. Gebhardt	241	Exciton-longitudinal optical phonon coupling in a ZnSe– $Zn_{0.75}Cd_{0.25}Se$ double-superlattice at 1.4 K
C.P. Yang, Y.Z. Wang, G.H. Wu, B.P. Hu, J. Du, X.F. Han, J.L. Wang, Z.L. Jiang and J. Zhu	247	Crystallographic and magnetic properties of a TB ₃ (Fe,Cr) ₂₉ single crystal
K.R. Allakhverdiev	253	Two-photon absorption in layered TlGaSe ₂ , TlInS ₂ , TlGaS ₂ and GaSe crystals
V.N. Narozhnyi, V.N. Kochetkov, A.V. Tsvyashchenko and L.N. Fomicheva	259	Hall effect study in YbNi ₂ B ₂ C borocarbide
S. Chaudhary, S.B. Roy and P. Chaddah	263	Anomalous peak-effect in CeRu ₂ : effect of disorder
D. Fuks	269	Integral thermodynamic properties of tungsten and molybdenum in effective potential approach
J. Bellessa and M. Combescot	275	Size dependance of impurity levels in quantum dots: exact versus variational results
D. Cherns, J. Barnard and F.A. Ponce	281	Measurement of the piezoelectric field across strained InGaN/GaN layers by electron holography
CH. Yan, ZG. Xu, FX. Cheng, ZM. Wang, LD. Sun, CS. Liao and JT. Jia	287	Nanophased CoFe ₂ O ₄ prepared by combustion method
	I	Keywords

VOLUME 111, NUMBER 6

(Published 9 July 1999)

	v	Editorial Note
C. Godet, T. Heitz, J.E. Bourée, B. Bouchet, J. Dixmier and B. Drévillon	293	Correlation between luminescence properties and microstructure of hydrogenated amorphous carbon films investigated by X-ray diffraction and infrared ellipsometry
S.E. Enescu, I. Bibicu, M.N. Grecu and A. Kluger	299	Recoilless Rayleigh scattering on Rb ₂ ZnCl ₄ around the normal-incommensurate phase transition point
R. Citro	305	Fermi surface evolution in the $p-d$ model
Z.P. Guan and T. Kobayashi	311	Electroreflection from higher subband transitions in a ZnSe-Zn _{0.8} Cd _{0.2} Se superlattice
M. Phillips and H. Wang	317	Coherent oscillation in four-wave mixing of interacting excitons
N. Randrianantoandro, E. Gaffet, J. Mira and JM. Greneche	323	Magnetic hyperfine temperature dependence in Fe-Si crystalline alloys
M. Gener, E. Canadell, S.S. Khasanov, L.V. Zorina, R.P. Shibaeva, L.A. Kushch and E.B. Yagubskii	329	Band structure and Fermi surface of the (BEDT-TTF) ₄ M[Fe $(CN)_5NO]_2$ (M = Na, K, Rb,) molecular metals containing the photochromic nitroprusside anion
J. Guevara, A.M. Llois, F. Aguilera-Granja and J.M. Montejano-Carrizales	335	Structural evolution of free Co cluster magnetism

Vol. 111, Nos 1-12 Contents

A. Thander and B. Mallik

341 Spectroscopic investigation on the photoinduced charge-transfer between ferrocene and chloroform molecules confined in a poly-(methyl methacrylate) thin film

S.-K. Park, M.-S. Baek, S.-C. Bae, S.-Y. Kwun,
K.-T. Kim and K.-W. Kim

347 Properties of LiNbO₃ thin film prepared from ceramic Li-Nb-K-O target

I Keywords

VOLUME 111, NUMBER 7

(Published 14 July 1999)

CONTENTS

	v	Editorial Note
HJ. Koo and MH. Whangbo	353	Analysis of the spin-spin interactions in layered oxides α' -NaV ₂ O ₅ , CaV ₂ O ₅ and MgV ₂ O ₅ and the spin-Peierls distortion in α' -NaV ₂ O ₅ by molecular orbital, Madelung energy and bond valence sum calculations
B.Sh. Bagautdinov, M.S. Novikova, I.P. Aleksandrova, M.K. Blomberg and G. Chapuis	361	X-ray study of phase transitions in Cs ₃ Sb ₂ I ₉ crystal
G.M. Maksimova, D.Yu. Vodolazov, M.V. Balakina and I.L. Maksimov	367	Effect of an edge barrier on magnetization and higher harmonics of a.csusceptibility of narrow superconducting film
A. Sekiyama, S. Suga, Y. Saitoh, S. Ueda, H. Harada, T. Matsushita, T. Nakatani, T. Iwasaki, K. Matsuda, M. Kotsugi, S. Imada, T. Takabatake, T. Yoshino, D.T. Adroja, R. Takayama, O. Sakai, H. Harima and T. Nanba	373	High resolution Ce 3d-4f resonant photoemission study of CeNiSn and CePdSn
P.D. Altukhov and E.G. Kuzminov	379	Condensation of a hot electron-hole plasma in tunneling silicon MOS structures
H.J. Choi and J. Ihm	385	Exact solutions to the tight-binding model for the conductance of carbon nanotubes
E.G. Maksimov, P.I. Arseyev and N.S. Maslova	391	Phonon assisted tunneling in Josephson junctions
R.I. Mashkovtsev and Yu.N. Pal'yanov	397	EPR of new nickel-nitrogen center in annealed synthetic diamond
Hua Wu, Zhi Zeng and Qing-qi Zheng	403	Influences of a non-spherical charge density upon the electronic structure of magnetic compounds
	I	Keywords

VOLUME 111, NUMBER 8

(Published 23 July 1999)

CONTENTS

Editorial Note

S.V. Korepov and M.A. Liberman

409 Scattering from defects in double quantum wires

Q. Huang, S. Pietzonka and R.G. Ulbrich

Raman scattering on crystallites growing at the interface of Au and amorphous Si during annealing

T. Hirata	421	Orientation dependence of infrared spectra on thermal oxidation and subsequent etching of single crystal Si
U. Pal and J. Garcia-Serrano	427	Infrared absorption and evidence of Si ₃ nanocluster formation in Si/ZnO composites
S. Dusane, T. Bhave, S. Hullavard, S.V. Bhoraskar and S. Lokhare	431	Electron exo-emission study of PECVD and thermal CVD sili- con rich silicon oxide
M. Abbate, G. Zampieri, F. Prado, A. Caneiro and A.R.B. de Castro	437	Comparative study of the unoccupied electronic structure of $La_{1-x}Ca_xMnO_3$ and $LaMnO_{3+\delta}$ using O 1s X-ray absorption spectroscopy
V.P. Dymont, E.M. Nekrashevich and I.M. Starchenko	443	Initial description of a bulk crystalline carbon-nitride phase
N. Nogi, S. Tanaka, T. Noda and T. Hirata	447	Infrared-active A_{2u} and E_u modes in isotopically enriched β -rhombohedral boron
A. Paolone, P. Roy, G. Rousse, C. Masquelier and J. Rodriguez-Carvajal	453	Infrared spectroscopy investigation of the charge ordering transition in LiMn_2O_4
E. Rauls, J. Elsner, R. Gutierrez and Th. Frauenheim	459	Stoichiometric and non-stoichiometric (1010) and (1120) surfaces in 2H-SiC: a theoretical study
	I	Author Index
	V	Keywords

(Published 29 July 1999)

CONTENTS		
v	Editorial Note	
465	Positron study of α-uranium	
471	Glass transition in the organic superconductor with the highest T_c under ambient pressure, κ -(ET) ₂ Cu[N(CN) ₂]Br	
477	Correlated d-states in the perovskites KFeF3 and KCoF3	
483	Optical properties of ZnS:Cu colloid prepared with sulfurous ligands	
489	Effect of hydrogenation on the electrical and optical properties of p-type $Zn_{1-x}Mg_xS_ySe_{1-y}$ epitaxial layers grown on GaAs (100) substrates	
495	Entangled photon pairs from the optical decay of biexcitons	
501	Quantum point contact in a compressible Quantum Hall liquid	
507	Anisotropy in the optical response of $(TMTTF)_2X$ $(X = PF_6$ and Br) Bechgaard salts	
513	Evidence for strong electron-phonon interaction from inelastic tunneling of Cooper pairs in c-direction in Bi ₂ Sr ₂ CaCu ₂ O ₈ break junctions	
519	Hydrogen induced structural and magnetic transformation in the $SmMn_2H_2$ compound	
I	Keywords	
	v 465 471 477 483 489 495 501 507 513	

(Published 10 August 1999)

CONTENTS

R. Mahendiran, M.R. Ibarra, A. Maignan, C. Martin, B. Raveau and A. Hernando	525	A possible origin of colossal magnetoresistance in charge-ordered manganate $La_{0.5}Ca_{0.5}MnO_3$
N.V. Chandra Shekar, P.C. Sahu, M. Yousuf, K. Govinda Rajan and M. Rajagopalan	529	Structural stability and compressibility behaviour of dialuminides of cerium and gadolinium under high pressure
P.H. Bucksbaum and R. Merlin	535	The phonon Bragg switch: a proposal to generate sub-pico- second X-ray pulses
H.Q. Fan, L.T. Zhang, L.Y. Zhang and X. Yao	541	Non-Debye relaxation and the glassy behavior of disordered perovskite ferroelectrics
S.K. Joshi and A.M. Jayannavar	547	Successive crossover from ordinary Born scattering to multiple scattering to localization: a delay time analysis in electronically random systems
M. Koch, S.T. Cundiff, W.H. Knox, J. Shah and W. Stolz	553	Magnetoexciton quantum beats: influence of Coulomb correlations
M. Taniguchi, Y. Misaki, T. Yamabe, K. Tanaka, K. Murata and T. Mori	559	(CPDT-STF) (TCNQ): a new charge-transfer complex metallic down to low temperature
F. Brosens, J.T. Devreese, V.M. Fomin and V.V. Moshchalkov	565	Superconductivity in a wedge: analytical variational results
M. Dubois, A. Merlin and D. Billaud	571	Electron spin resonance in lithium and sodium electrochemically intercalculated poly(paraphenylene)
L.Q. Wu, M.C. Huang, S.P. Li, Z.Z. Zhu and B.H. Zhuang	577	Conduction-band-edge variations of pseudomorphic $Si_{1-x-y}Ge_xC_y$ alloys grown on (110) Si and Ge substrates
L. De Santis and R. Resta	583	Surface reconstructions and bonding via the electron localization function: the case of Si(001)
S.N. Klimin, V.M. Fomin, J.T. Devreese and V.V. Moshchalkov	589	Superconductivity in a wedge with a small angle: an analytical treatment
	I	Keywords

VOLUME 111, NUMBER 11

(Published 17 August 1999)

T. Pusztai, G. Oszlányi, G. Faigel, K. Kamarás,L. Gránásy and S. Pekker	595	Bulk structure of phototransformed C ₆₀
A. Bhattacharjee	601	Effect of non-magnetic organic cation (A) on the magnetic properties of $ANi^{II}[Fe^{III}(ox)_3]$, $A = N(n-C_4H_9)_4^+$ and $N(n-C_3H_7)_4^+$
M. Mito, T. Kawae, Y. Hosokoshi, K. Inoue, M. Kinoshita and K. Takeda	607	Pressure-induced crossover from alternating to uniform interaction in a $S = 1/2$ one-dimensional Heisenberg antiferromagnet
J. Cieślak, S.M. Dubiel and B. Sepiol	613	In situ Mössbauer-effect study of the kinetics of the σ -phase formation
D. Selvanathan, W.J. Bresser, P. Boolchand and B. Goodman	619	Thermally reversing window and stiffness transitions in chalco- genide glasses
G. Kuang, W. Gebhardt, E. Griebl, U. Boell, A. Kronschnabel, H. Preis and G. Lautner	625	Observation of strong biexcitonic luminescence in ZnMgSe/ZnSe single quantum well

G.J. Hu, L. Zhang, N. Dai, L.Y. Chen and M.C. Tamargo	631	Persistent photoconductivity in Ga δ-doped ZnSe
K.K. Tiong, C.H. Ho and Y.S. Huang	635	The electrical transport properties of ReS_2 and $ReSe_2$ layered crystals
W. Cheng, J.B. Xia, M.S. Jeong, X.L. Huang, J.Y. Kim, S.H. Ihm, EK. Suh and H.J. Lee	641	Observation of field-driven blue shift in δ -doped Si $n{-}i{-}p{-}i$ multiple quantum wells
SL. Zhang, BF. Zhu, F. Huang, Y. Yan, Ey. Shang, S. Fan and W. Han	647	Effect of defects on optical phonon Raman spectra in SiC nanorods
WS. Liu and SJ. Xiong	653	Metal-insulator transition in anisotropic system with a random magnetic field
G. Li, S.J. Chua and W. Wang	659	The Hall mobility and its relationship to the persistent photo-conductivity of undoped GaN
	I	Keywords

(Published 24 August 1999)

		· · · · · · · · · · · · · · · · · · ·
	v	Editorial Note
F.M. Munteanu, Yongmin Kim, C.H. Perry, D.G. Rickel, J.A. Simmons and J.L. Reno	665	Photoluminescence detected doublet structure in the integer and fractional quantum Hall regime
K.K. Nanda and S.N. Sahu	671	Photoluminescence of CdS nanocrystals: effect of ageing
G.Kh. Azhdarov, R.Z. Kyazimzade and M. Hostut	675	Deep impurity levels in $Ge_{1-x}Si_x$ alloys
C.H. Chen and Y.F. Chen	681	Optical properties of n-type porous silicon obtained by photo- electrochemical etching
R. Przeniosło, I. Sosnowska, D. Hohlwein, T. Hauß and I.O. Troyanchuk	687	Magnetic ordering in the manganese perovskite CaMn ₇ O ₁₂
K. Murayama, N. Katagiri, S. Miyazaki and M. Hirose	693	Thermalization gaps of the ultra-thin a-Si:H well layers in a-Si:H/a-Si ₃ N ₄ :H multilayers
A. Kuriyama, S. Takaoka, K. Oto, K. Murase,S. Shimomura, S. Hiyamizu, M. Chkr,T. Jungwirth and L. Smrčka	699	Cyclotron resonance in double-layer two-dimensional electron system in tilted magnetic fields
W.J. Yu, Y.I. Kim, D.H. Ha, J.H. Lee, Y.K. Park, S. Seong and N.H. Hur	705	A new manganese oxide with the Aurivillius structure: $Bi_2Sr_2Nb_2MnO_{12-\delta}$
O.A. Shlyakhtin, Young-Jei Oh and Yu.D. Tretyakov	711	Influence of chemical prehistory on the colossal magneto- resistance of La _{0.7} Ca _{0.3} MnO ₃ ceramics
F.J. García-Rodríguez, F. Pérez-Robles, A. Manzano-Ramírez, Y.V. Vorobiev and J. González-Hernández	717	Oxygen diffusion in silica glass prepared by the sol-gel method
Y.D. Juang, S.B. Dai, Y.C. Wang, W.Y. Chou, J.S. Hwang, M.L. Hu and W.S. Tse	723	Phase transition of Li _x Na _{1-x} NbO ₃ studied by Raman scattering method
A. Nag, A. Sengupta and D. Ghosh	729	Study of the magnetic susceptibility and anisotropy properties of Tm ³⁺ diglycollate crystal for evaluating crystal field effects
A.S. Shalabi, M.M. Assem, S. Abdel-Aal, M.A. Kamel and M.M. Abd El-Rahman	735	Adsorption of He and Ne on regular, irregular and defected surfaces of LiH crystal: ab initio study
O.M. Schmitt, L. Bányai and H. Haug	741	Exciton and biexciton correlations for weakly confined semi- conductor quantum wires

H.J. Lozykoswki, W.M. Jadwisienczak and I. Brown

- 747 Corrigendum: Cathodoluminescence of GaN doped with Sm and Ho
 - I Volume III Index
- XI Author Index
- XVII Keywords

